

RJK0703DPP-A0

N-Channel MOS FET
75 V, 70 A, 6.7 mΩ

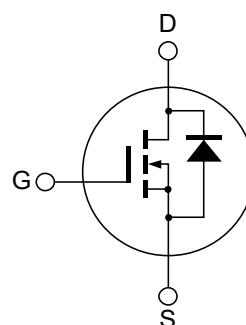
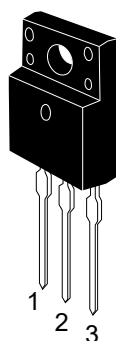
R07DS1443EJ0101
Rev.1.01
2020.1.9

Features

- High speed switching
- Low drive current
- Low on-resistance $R_{DS(on)} = 5.3 \text{ m}\Omega$ typ. (at $V_{GS} = 10 \text{ V}$)
- Package TO-220FPA
- Quality Grade : Standard

Outline

Renesas Package code:PRSS0003AP-A
(Package name:TO-220FPA)



1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	75	V
Gate to source voltage	V_{GSS}	± 20	V
Drain current	I_D Note1	70	A
Drain peak current	I_D (pulse) Note2	210	A
Body-drain diode reverse drain current	I_{DR}	70	A
Avalanche current	I_{AP} Note3	35	A
Avalanche energy	E_{AS} Note3	184	mJ
Channel dissipation	P_{ch} Note1	25	W
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

Note: Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect a reliability even if it is within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook (Recommendation for Handling and Usage of Semiconductor Devices) and individual reliability data.

Notes: 1. $T_c = 25^\circ\text{C}$

2. $PW \leq 10 \mu\text{s}$, duty cycle $\leq 1\%$

3. Value at $L = 100 \mu\text{H}$, $T_{ch} = 25^\circ\text{C}$, $R_g \geq 50\Omega$,

Thermal Impedance

Item	Symbol	Max. Value ^{Note4}	Unit
Channel to case thermal impedance	θ_{ch-c}	5.0	°C/W

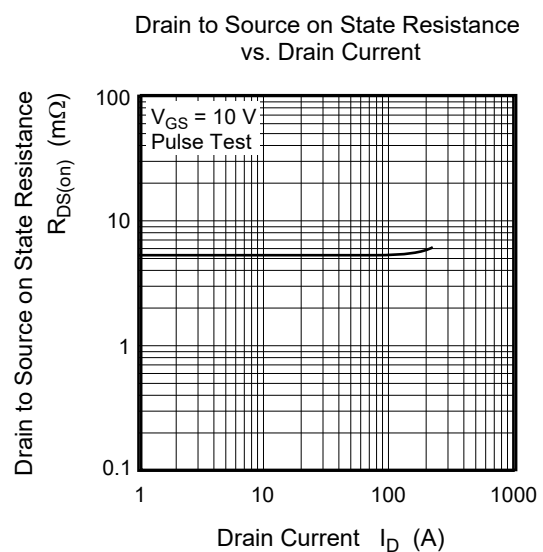
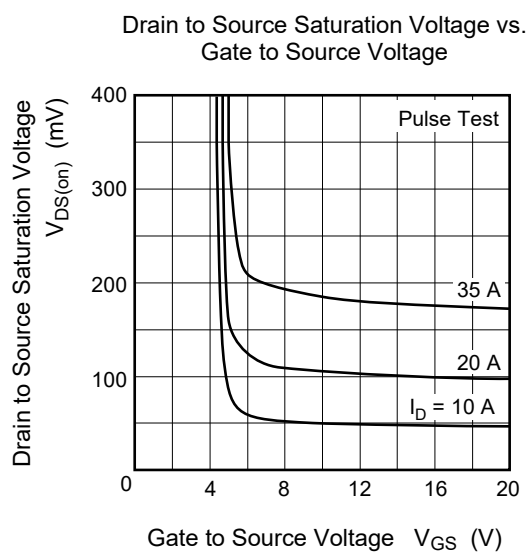
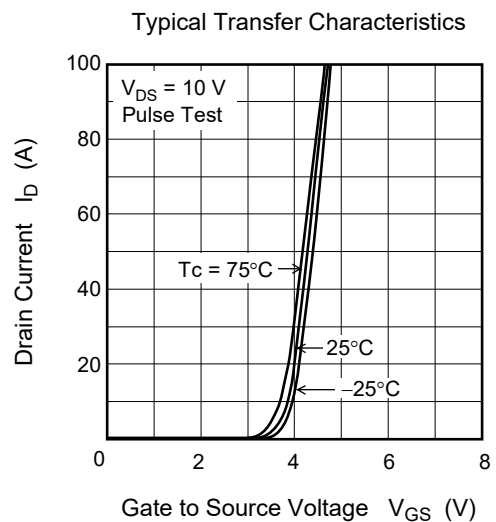
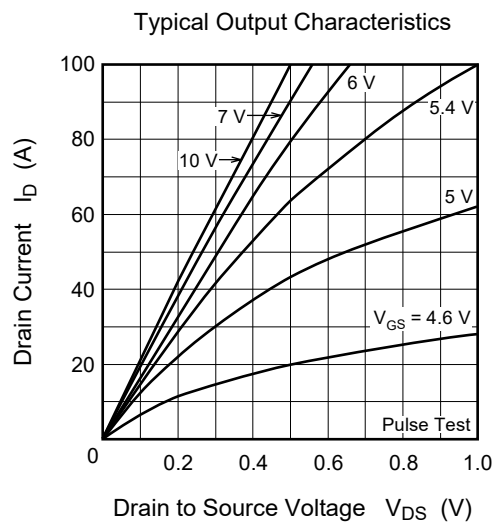
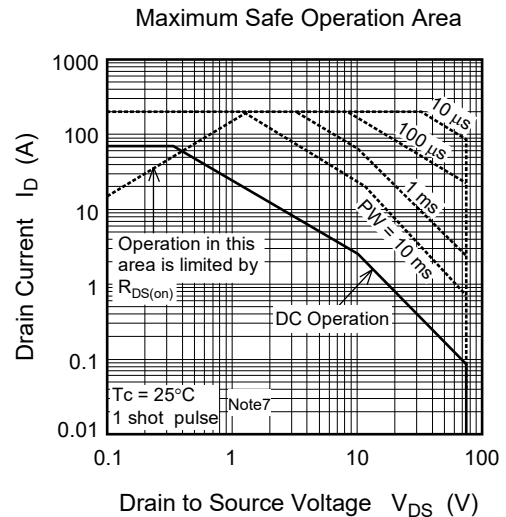
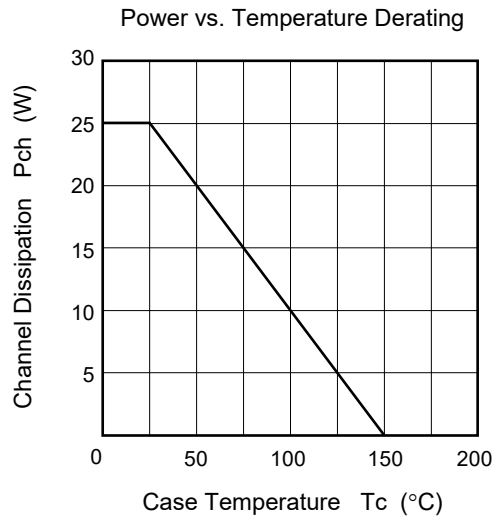
Notes: 4. This data is the designed target maximum value on Renesas's measurement condition. (Not tested)

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	75	—	—	V	$I_D = 10\text{mA}$, $V_{GS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 0.1	μA	$V_{GS} = \pm 20\text{V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	1	μA	$V_{DS} = 75\text{V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	4.0	V	$V_{DS} = 10\text{V}$, $I_D = 1\text{mA}$
Static drain to source on state resistance	$R_{DS(on)}$	—	5.3	6.7	$\text{m}\Omega$	$I_D = 35\text{A}$, $V_{GS} = 10\text{V}$ ^{Note5}
Forward transfer admittance	$ y_{fs} $	—	90	—	S	$I_D = 35\text{A}$, $V_D = 10\text{V}$ ^{Note5}
Input capacitance	C_{iss}	—	4150	—	pF	$V_{DS} = 10\text{V}$ $V_{GS} = 0$ $f = 1\text{MHz}$
Output capacitance	C_{oss}	—	830	—	pF	
Reverse transfer capacitance	C_{rss}	—	200	—	pF	
Gate Resistance	R_g	—	1.6	—	Ω	
Total gate charge	Q_g	—	56	—	nC	$V_{DD} = 25\text{V}$ $V_{GS} = 10\text{V}$, $I_D = 35\text{A}$
Gate to source charge	Q_{gs}	—	20	—	nC	
Gate to drain charge	Q_{gd}	—	8	—	nC	
Turn-on delay time	$t_{d(on)}$	—	30	—	ns	$V_{GS} = 10\text{V}$ $I_D = 35\text{A}$ $V_{DD} \cong 30\text{V}$ $R_g = 4.7\Omega$
Rise time	t_r	—	10	—	ns	
Turn-off delay time	$t_{d(off)}$	—	60	—	ns	
Fall time	t_f	—	11	—	ns	
Body-drain diode forward voltage	V_{DF}	—	0.85	1.5	V	$I_F = 70\text{A}$, $V_{GS} = 0$ ^{Note5}
Body-drain diode reverse recovery time	t_{rr}	—	50	—	ns	$I_F = 70\text{A}$, $V_{GS} = 0$ $di_F/dt = 100\text{A}/\mu\text{s}$

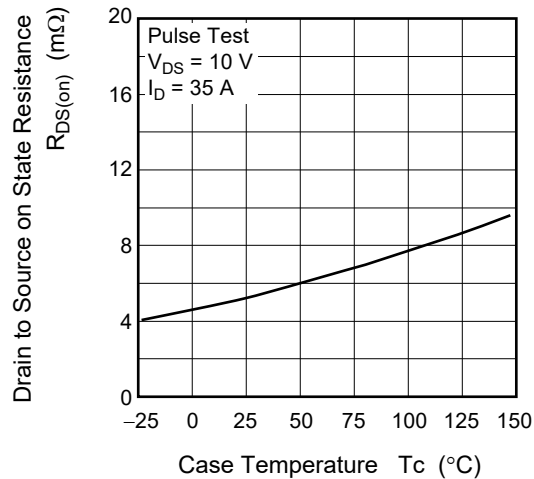
Notes: 5. Pulse test

Typical Characteristics Note6

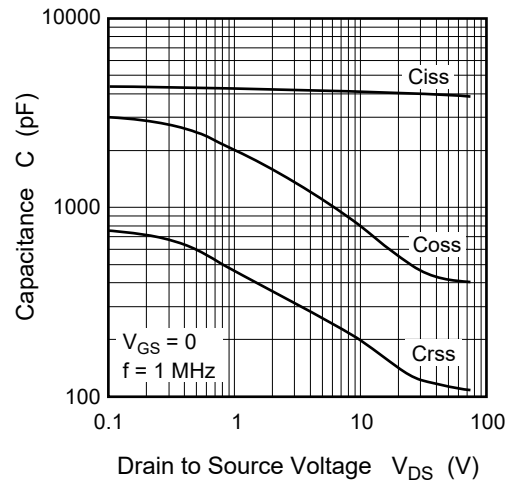
Notes: 6. Designed target value on Renesas measurement condition.

7. This data is the designed value on Renesas's measurement condition. Renesas recommends that operating conditions are designed according to a document "Power MOSFET/IGBT Attention of Handling Semiconductor Devices (R07ZZ0010)".

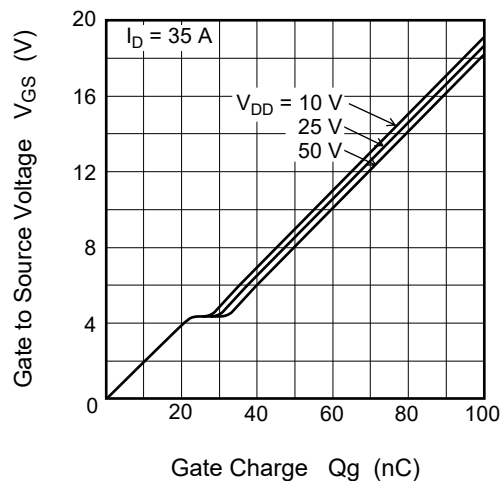
Drain to Source on State Resistance
vs. Temperature



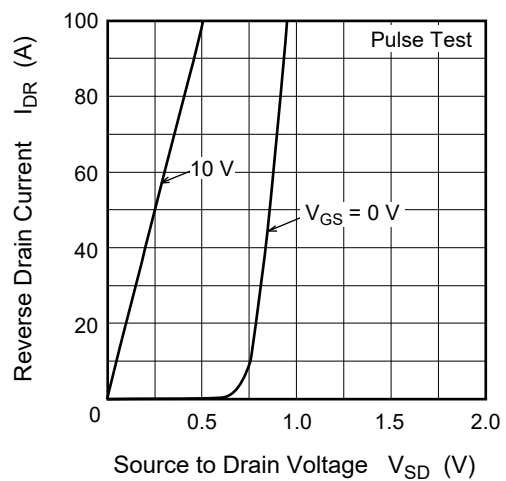
Typical Capacitance vs.
Drain to Source Voltage



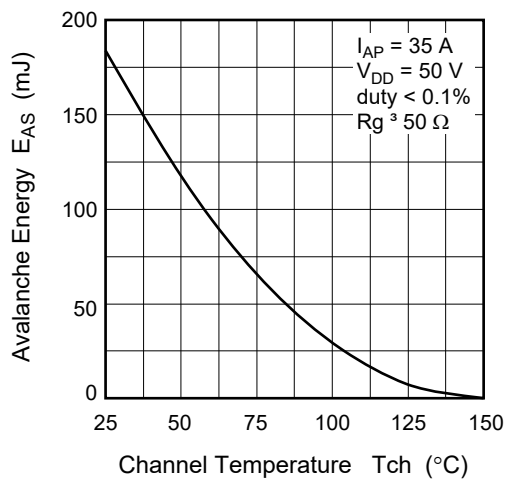
Dynamic Input Characteristics



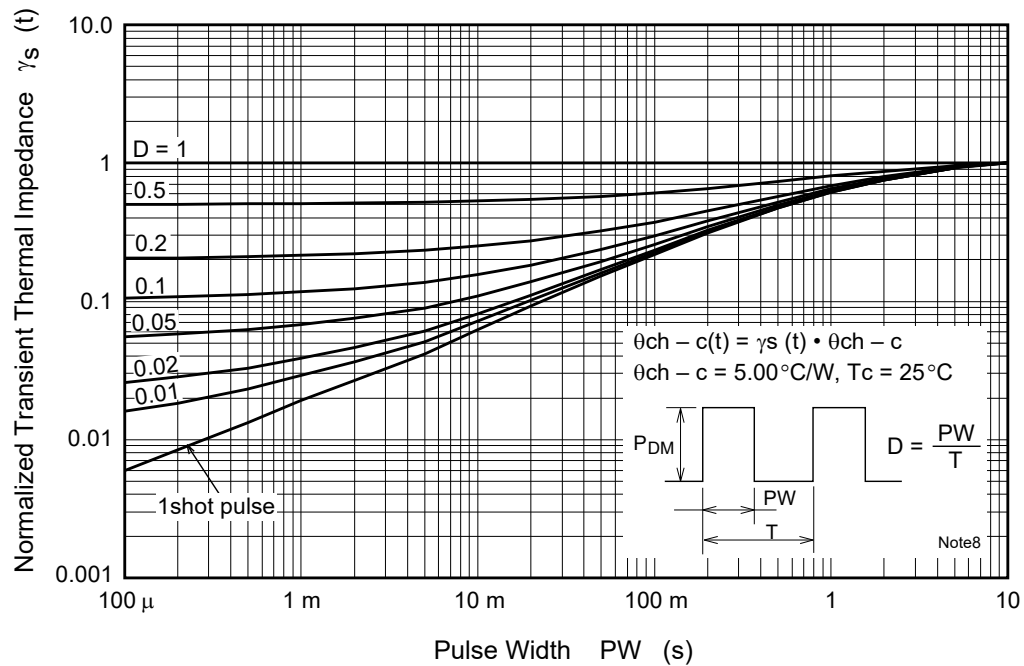
Reverse Drain Current vs.
Source to Drain Voltage



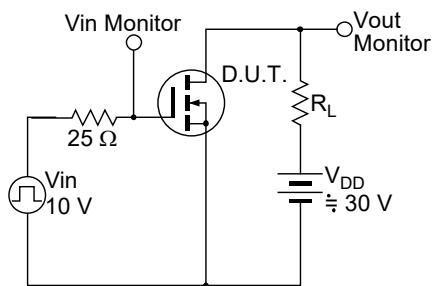
Maximum Avalanche Energy vs.
Channel Temperature Derating



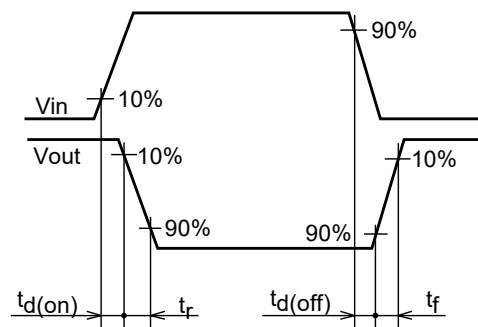
Normalized Transient Thermal Impedance vs. Pulse Width



Switching Time Test Circuit



Waveform

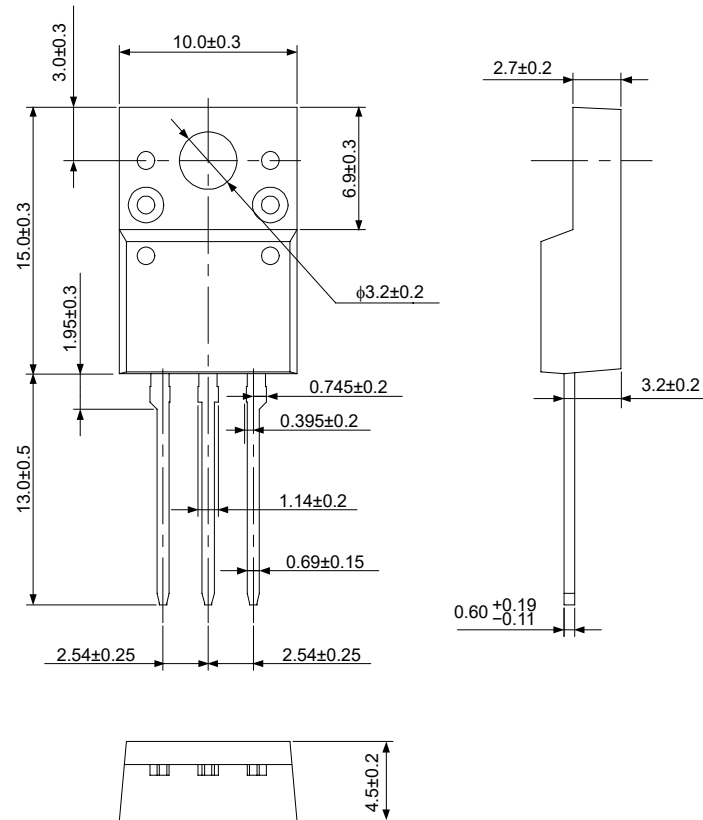


Notes: 8. This data is the designed target maximum value on Renesas's measurement condition.

Package Dimensions

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS (Typ) [g]
TO-220FPA	—	PRSS0003AP-A	TO-220FPA	1.65

Unit: mm



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK0703DPP-A0-T2	50 pcs	Magazine (Tube)

Note: The symbol of 2nd "-" is occasionally presented as "#".

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